



UNITED STATES PATENT AND TRADEMARK OFFICE

UNITED STATES DEPARTMENT OF COMMERCE
United States Patent and Trademark Office
Address: COMMISSIONER OF PATENTS AND TRADEMARKS
Washington, D.C. 20231
www.uspto.gov

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/292,132	04/14/1999	SALMAN AKRAM	MI22-1171	3104

21567 7590 10/02/2002

WELLS ST. JOHN ROBERTS GREGORY & MATKIN P.S.
601 W. FIRST AVENUE
SUITE 1300
SPOKANE, WA 99201-3828

EXAMINER

MULPURI, SAVITRI

ART UNIT	PAPER NUMBER
----------	--------------

2812

DATE MAILED: 10/02/2002

Please find below and/or attached an Office communication concerning this application or proceeding.

Office Action Summary

Application No.

09/292,132

Applicant(s)

Akram et al

Examiner

Savitri Mulpuri

Art Unit

2812

— The MAILING DATE of this communication appears on the cover sheet with the correspondence address —

Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136 (a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If the period for reply specified above is less than thirty (30) days, a reply within the statutory minimum of thirty (30) days will be considered timely.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133).
- Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

- 1) ☒ Responsive to communication(s) filed on Aug 14, 2002.
- 2a) ☐ This action is **FINAL**. 2b) ☒ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11; 453 O.G. 213.

Disposition of Claims

- 4) ☒ Claim(s) 51-53, 55-59, and 62-83 is/are pending in the application.
- 4a) Of the above, claim(s) _____ is/are withdrawn from consideration.
- 5) ☒ Claim(s) 62-67 and 80 is/are allowed.
- 6) ☒ Claim(s) 51-53, 55-59, 68-79, and 81-83 is/are rejected.
- 7) ☐ Claim(s) _____ is/are objected to.
- 8) ☐ Claims _____ are subject to restriction and/or election requirement.

Application Papers

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☐ The drawing(s) filed on _____ is/are a) ☐ accepted or b) ☐ objected to by the Examiner.
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
- 11) ☐ The proposed drawing correction filed on _____ is: a) ☐ approved b) ☐ disapproved by the Examiner.
If approved, corrected drawings are required in reply to this Office action.
- 12) ☐ The oath or declaration is objected to by the Examiner.

Priority under 35 U.S.C. §§ 119 and 120

- 13) ☐ Acknowledgement is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
a) ☐ All b) ☐ Some* c) ☐ None of:
1. ☐ Certified copies of the priority documents have been received.
2. ☐ Certified copies of the priority documents have been received in Application No. _____.
3. ☐ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).
*See the attached detailed Office action for a list of the certified copies not received.
- 14) ☐ Acknowledgement is made of a claim for domestic priority under 35 U.S.C. § 119(e).
a) ☐ The translation of the foreign language provisional application has been received.
- 15) ☐ Acknowledgement is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121.

Attachment(s)

- 1) ☐ Notice of References Cited (PTO-892) 4) ☐ Interview Summary (PTO-413) Paper No(s). _____
- 2) ☐ Notice of Draftsperson's Patent Drawing Review (PTO-948) 5) ☐ Notice of Informal Patent Application (PTO-152)
- 3) ☐ Information Disclosure Statement(s) (PTO-1449) Paper No(s). _____ 6) ☐ Other:

Art Unit:

DETAILED ACTION

This action is in response to the applicant's arguments filed on 6/13/02.

Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

Claims 51-53 , 76-78, 82-83 are rejected under 35 U.S.C. 103(a) as being unpatentable over Suzuki et al or Oikawa(JP5-102067 from IDS) in combination with Pan '525

Suzuki et al and Oikawa discloses a method of making a device by the following process steps. Providing a substrate, forming gate oxide layer and then annealing in any halogen elemental such as chlorine(Suzuki) injection technique by Oikawa and forming polysilicon gate electrode.

Both Suzuki et al and Oikawa do not disclose concentration of fluorine . Oikawa even

Art Unit:

disclose insitu doping of chlorine in gate oxide (see page 5, lines 1-12) in translation document).

Pan '525 discloses diffusion of fluorine into gate oxide at the concentration of $5 \times 10^{20}/\text{cm}^3$ (see col. 5, lines 15-27). It would have been obvious to one of ordinary skill in the art to have concentration in the invention of Suzuki or Oikawa because such concentration only at edges of the gate oxide in Pan is suitable for hot electron carrier suppression.

Claims 55-59, 68-75, 79, 81 are rejected under 35 U.S.C. 103(a) as being unpatentable over Gardner et al in Pan '525

Gardener et al disclose a method of making a FET device by the following process steps:
Providing a gate oxide layer on as surface of a substrate; forming a gate electrode on gate oxide layer, wherein side walls of the gate oxide and gate electrode are aligned; forming side walls spacers on the aligned side walls of the gate oxide and gate electrode, wherein side walls having fluorine either by doping or ion implantation; heat-treating the substrate with spacer in nitrogen ambient to suppress hot carrier effect (see col. 3-col. 5). Claim 68 is limited to "forming spacers with chlorine or fluorine only on lateral edge of the gate and not how spacers or formed with respect to gate oxide

Art Unit:

Gardener et al do not disclose (1) concentration of the fluorine in the range of 1×10^{19} to $1 \times 10^{21} / \text{cm}^3$ and concentration depth not more than 500 angstroms (3) forming gate oxide extending laterally past the lateral edges of the gate.

Pan '525 discloses diffusion of fluorine into gate oxide at the concentration of $5 \times 10^{20} / \text{cm}^3$ (see col. 5, lines 15-27)

Claims 62-67, 80 are allowed because spacers containing fluorine are formed on gate oxide is not taught in the prior art.

Applicant's arguments with respect to claims 51-59, 62-83 have been considered but are moot in view of the new ground(s) of rejection.

.Any inquiry concerning this communication or earlier communications from the examiner should be directed to S. Mulpuri whose telephone number is (703) 305-5184. The fax phone number for the organization where this application or proceeding is assigned is (703) 308-7722.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956.


SAVITRI MULPURI
PRIMARY EXAMINER